NSN 5962-01-076-8401

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View Online at https://aerobasegroup.com/nsn/5962-01-076-8401

| • | |
|------------------------|--|
| Body Length: | |
| 0.440 inches | |
| Body Width: | |
| Between 0.248 inche | s and 0.325 inches |
| Body Height: | |
| 0.085 inches | |
| Maximum Power Dis | sipation Rating: |
| 910.0 milliwatts | |
| Operating Tempurat | ure Range: |
| -55.0/+125.0 degrees | celsius |
| Storage Tempuratur | e Range: |
| -65.0/+150.0 degrees | celsius |
| Features Provided: | |
| Hermetically sealed a | nd monolithic and positive outputs and w/storage and programmable and programmed and bipolar and 3-state output |
| and schottky and high | speed and expandable and w/buffered output and w/decoded output and w/enable and w/disable |
| Inclosure Material: | |
| Ceramic and glass | |
| Inclosure Configura | tion: |
| Flat pack | |
| Output Logic Form: | |
| Transistor-transistor | ogic |
| Input Circuit Pattern | : |
| 6 input | |
| Terminal Surface Tr | eatment: |
| Solder | |
| Voltage Rating And | Type Per Characteristic: |
| 5.5 volts power source | |
| Time Rating Per Cha | acteristic: |
| 40.00 nanoseconds | propagation delay time, low to high level output and 84.00 nanoseconds propagation delay time, high to low level |
| output | |
| Memory Device Typ | 8: |
| Rom | |
| Memory Capacity: | |
| Unknown | |
| Test Data Document | |
| 82577-932821 standa | ard (includes industry or association standards, individual manufactureer standards, etc.). |
| Terminal Type And | |
| 16 flat leads | |
| Shelf Life: | |
| N/a | |
| Unit Of Measure: | |
| | |
| Demilitarization: | |

Yes - demil/mli

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